



## **Transient Voltage Suppressors for ESD Protection**

### **General Description**

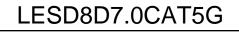
The LESD8D7.0CAT5G is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium.

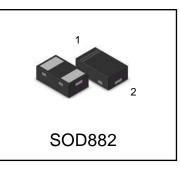
### Applications

- Cellular phones
- Portable devices
- Digital cameras
- Power supplies

#### Features

- Small Body Outline Dimensions
- Low Body Height
- Peak Power up to 80 Watts @ 8 x 20 µs Pulse
- Low Leakage
- Response Time is Typically < 1 ns
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- IEC61000–4–2 Level 4 ESD Protection
- IEC61000–4–4 Level 4 EFT Protection
- We declare that the material of product compliance with RoHS requirements.





#### ORDERING INFORMATION

Device	Marking	Package	Shipping	
LESD8D7.0CAT5G	R2	SOD-882	10000/Tape & Reel	

Symbol	Parameter	Value	Units
P <sub>PP</sub>	Peak Pulse Power (t <sub>p</sub> = 8/20µs)	80	W
TL	Maximum lead temperature for soldering during 10s	260	°C
T <sub>stg</sub>	Storage Temperature Range	-55 to +150	°C
T <sub>op</sub>	Operating Temperature Range	-40 to +125	°C
Tj	Maximum junction temperature	150	°C
	IEC61000-4-2 (ESD) air discharge contact discharge	±20 ±15	ΚV
	IEC61000-4-4 (EFT)	40	А
	ESD Voltage Per Human Body Model	16	KV

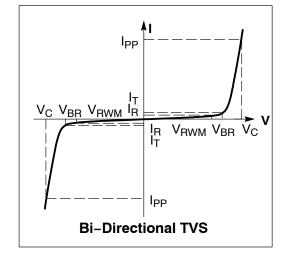
#### Absolute Ratings (T<sub>amb</sub>=25°C)



# LESD8D7.0CAT5G

## **Electrical Parameter**

Symbol	Parameter
	Movimum Dovoroo Dook Duloo Curront
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current
V <sub>C</sub>	Clamping Voltage @ IPP
$V_{RWM}$	Working Peak Reverse Voltage
I <sub>R</sub>	Maximum Reverse Leakage Current @ $V_{\text{RWM}}$
Ι <sub>Τ</sub>	Test Current
$V_{BR}$	Breakdown Voltage @ I <sub>T</sub>
١ <sub>F</sub>	Forward Current
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>

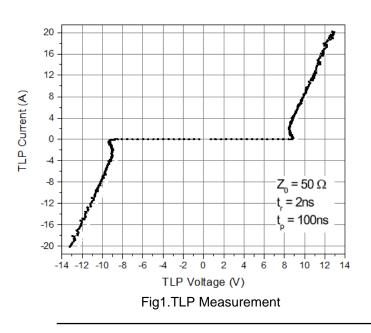


Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.VF = 0.9V at IF = 10mA

Device	V <sub>RWM</sub> (V)	I <sub>R</sub> (uA) @ V <sub>RWM</sub>	V <sub>BR</sub> (V)@ ┠ (Note 1)	L_	V <sub>c</sub> (V) @ I <sub>PP</sub> =3 A*	V <sub>C</sub> (V) @ Max I <sub>PP</sub> *	І <sub>РР</sub> (А)*	Р <sub>РК</sub> (W)*	C (pF)
	Max	Max	Min	mA	Тур	Max	Мах	Max	Тур
LESD8D7.0CAT5G	7.0	1.0	7.2	1.0	13	16	5	80	16

\*Surge current waveform per Figure 2.

1.  $V_{BR}$  is measured with a pluse test current  $I_T$  at an ambient temperature of  $25\,^\circ\!\!\mathbb{C}$  .





# LESD8D7.0CAT5G

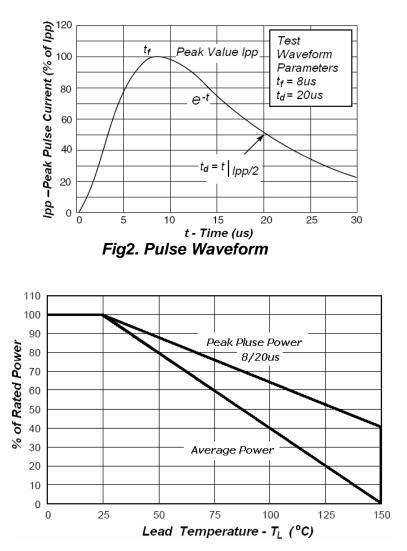


Fig3.Power Derating

### **Application Note**

Electrostatic discharge (ESD) is a major cause of failure in electronic systems. Transient Voltage Suppressors (TVS) are an ideal choice for ESD protection. They are capable of clamping the incoming transient to a low enough level such that damage to the protected semiconductor is prevented.

Surface mount TVS offer the best choice for minimal lead inductance. They serve as parallel protection elements, connected between the signal line to ground. As the transient rises above the operating voltage of the device, the TVS becomes a low impedance path diverting the transient current to ground. The LESD8D7.0CT5G is the ideal board evel protection of ESD sensitive semiconductor components.

The tiny SOD882 package allows design flexibility in the design of high density boards where the space saving is at a premium. This enables to shorten the routing and contributes to hardening againt ESD.

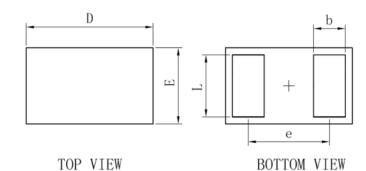




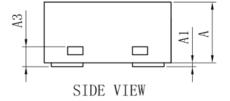
# LESD8D7.0CAT5G

#### OUTLINE AND DIMENSIONS

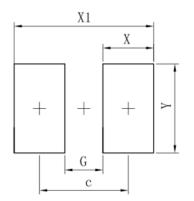
## S0D882



S0D882						
Dim	Min	Min Typ Max				
D	0.95 1.00 1.0		1.05			
Е	0.55	0.60	0.65			
е	- 0.64 -					
L	0.44	0.49	0.54			
b	0.20 0.25 0.30					
А	0.43	0.48	0.53			
A1	0 - 0.05					
A3	A3 0. 127REF.					
All Dimensions in mm						



SOLDERING FOOTPRINT



## S0D882

Dimensions	(mm)
с	0.70
G	0.30
Х	0.40
X1	1.10
Y	0.70